

### Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical application are in switching Mode Power Supplies such as adaptors, DC/DC converters, free-wheeling and polarity protection diodes.

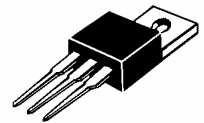
#### Features

- \* Low Forward Voltage.
- \* Low Switching noise.
- \* High Current Capacity
- \* Guarantee Reverse Avalanche.
- \* Guard-Ring for Stress Protection.
- \* Low Power Loss & High efficiency.
- \* 175°C Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- \* *In compliance with EU RoHs 2002/95/EC directives*
- \* Mounting Torque: 5 in-lbs.Max



#### SCHOTTKY BARRIER RECTIFIERS

**20 AMPERES  
150 VOLTS**



**TO-220AB**

### MAXIMUM RATINGS

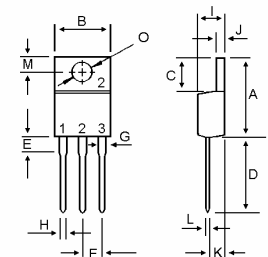
Characteristic	Symbol	S20T150CB	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	150	V
RMS Reverse Voltage	$V_{R(RMS)}$	105	V
Average Rectifier Forward Current ( per diode ) Total Device (Rated $V_R$ ),	$I_{F(AV)}$	10 20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	$I_{FSM}$	250	A
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +150	°C

### THERMAL RESISTANCES

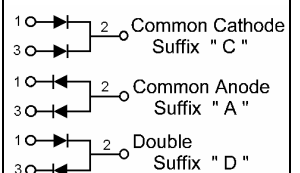
Typical Thermal Resistance junction to case ( per device )	$R_{\theta jc}$	3.6	°C/w
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### ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	Min	Typ.	Max	Unit
Maximum Instantaneous Forward Voltage ( per diode ) ( $I_F = 0.1$ Amp $T_C = 25^\circ C$ ) ( $I_F = 5.0$ Amp $T_C = 25^\circ C$ ) ( $I_F = 10$ Amp $T_C = 25^\circ C$ )	$V_F$	---	0.38 0.70 0.77	0.40 0.72 0.80	V
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25^\circ C$ ) ( Rated DC Voltage, $T_C = 125^\circ C$ )	$I_R$	---	0.003 5	0.01 7	mA



DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.32
B	9.78	10.42
C	5.02	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	2.66
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.98
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90



# S20T150CB

FIG-1 FORWARD CURRENT DERATING CURVE

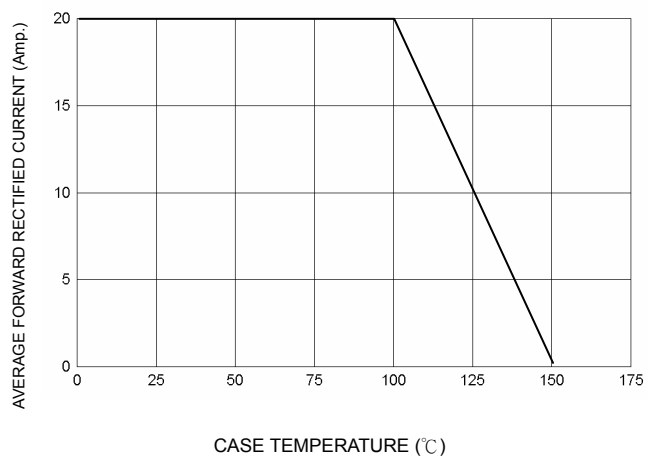


FIG-2 TYPICAL FORWARD CHARACTERISTICS

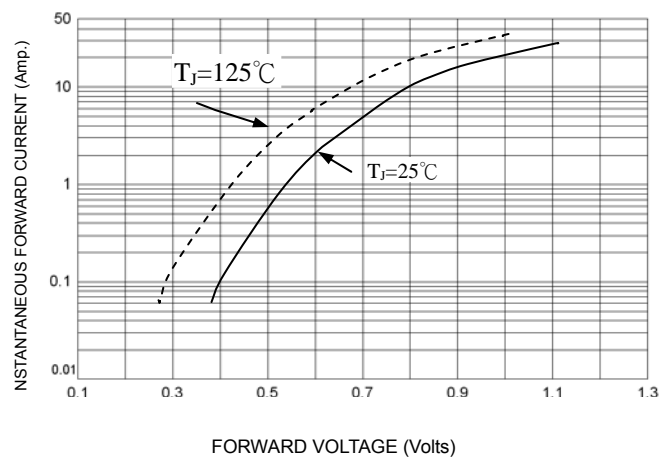


FIG-3 TYPICAL REVERSE CHARACTERISTICS

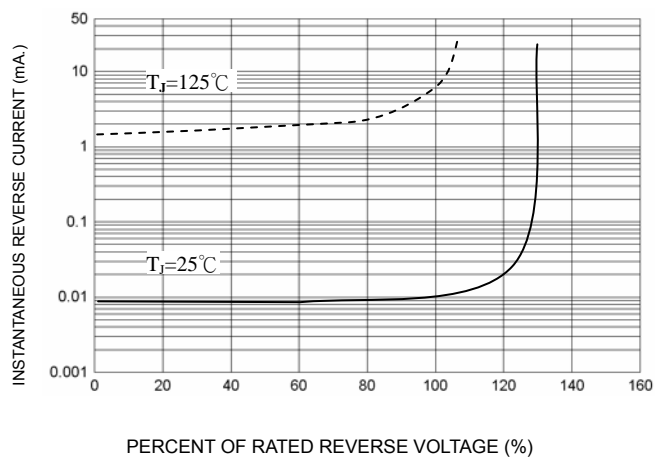


FIG-4 TYPICAL JUNCTION CAPACITANCE

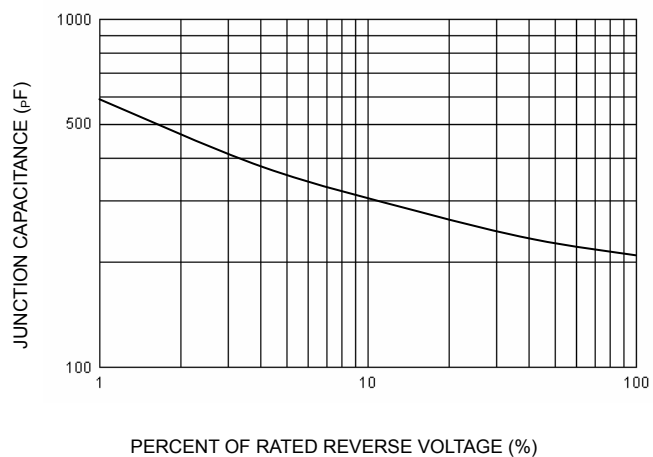


FIG-5 PEAK FORWARD SURGE CURRENT

